# 74AHC1G04; 74AHCT1G04

#### Inverter

Rev. 9 — 10 March 2015

Product data sheet

## 1. General description

74AHC1G04 and 74AHCT1G04 are high-speed Si-gate CMOS devices. They provide an inverting buffer.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

The AHCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

### 2. Features and benefits

- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- Multiple package options
- ESD protection:
  - ◆ HBM JESD22-A114E: exceeds 2000 V
  - ◆ MM JESD22-A115-A: exceeds 200 V
  - ◆ CDM JESD22-C101C: exceeds 1000 V
- Specified from –40 °C to +125 °C

## 3. Ordering information

Table 1. Ordering information

| Type number  | Package           |        |   |          |  |  |  |  |  |  |  |
|--------------|-------------------|--------|---|----------|--|--|--|--|--|--|--|
|              | Temperature range | Name   | Description                                   | Version  |  |  |  |  |  |  |  |
| 74AHC1G04GW  | -40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package;    | SOT353-1 |  |  |  |  |  |  |  |
| 74AHCT1G04GW |                   |        | 5 leads; body width 1.25 mm                   |          |  |  |  |  |  |  |  |
| 74AHC1G04GV  | -40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads      | SOT753   |  |  |  |  |  |  |  |
| 74AHCT1G04GV |                   |        |   |          |  |  |  |  |  |  |  |
| 74AHC1G04GM  | -40 °C to +125 °C | XSON6  | plastic extremely thin small outline package; | SOT886   |  |  |  |  |  |  |  |
| 74AHCT1G04GM |                   |        | no leads; 6 terminals; body 1 × 1.45 × 0.5 mm |          |  |  |  |  |  |  |  |



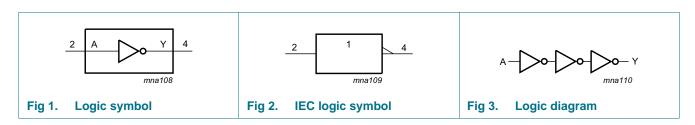
## 4. Marking

#### Table 2. Marking codes

| Type number  | Marking <sup>[1]</sup> |
|--------------|------------------------|
| 74AHC1G04GW  | AC                     |
| 74AHC1G04GV  | A04                    |
| 74AHC1G04GM  | AC                     |
| 74AHCT1G04GW | CC                     |
| 74AHCT1G04GV | C04                    |
| 74AHCT1G04GM | CC                     |

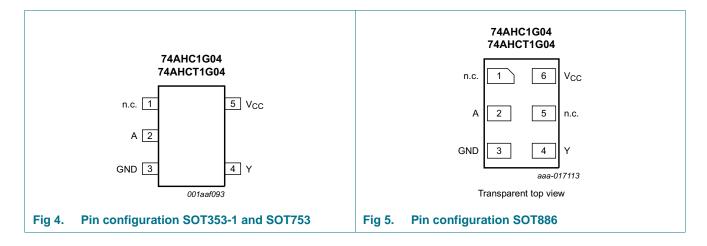
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram



## 6. Pinning information

### 6.1 Pinning



## 6.2 Pin description

Table 3. Pin description

| Symbol          | Pin                 |        | Description    |
|-----------------|---------------------|--------|----------------|
|                 | SOT353-1 and SOT753 | SOT886 |                |
| n.c.            | 1                   | 1      | not connected  |
| Α               | 2                   | 2      | data input     |
| GND             | 3                   | 3      | ground (0 V)   |
| Υ               | 4                   | 4      | data output    |
| n.c.            | -                   | 5      | not connected  |
| V <sub>CC</sub> | 5                   | 6      | supply voltage |

## 7. Functional description

#### Table 4. Function table

H = HIGH voltage level; L = LOW voltage level

| Input | Output |
|-------|--------|
| Α     | Υ      |
| L     | Н      |
| Н     | L      |

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions  |     | Min        | Max  | Unit |
|------------------|-------------------------|---|-----|------------|------|------|
| V <sub>CC</sub>  | supply voltage          |   |     | -0.5       | +7.0 | V    |
| VI               | input voltage           |   |     | -0.5       | +7.0 | V    |
| l <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < -0.5 V   |     | -20        | -    | mA   |
| ок               | output clamping current | $V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$                   | [1] | -          | ±20  | mA   |
| lo               | output current          | $-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$ |     | -          | ±25  | mA   |
| lcc              | supply current          |   |     | -          | 75   | mA   |
| I <sub>GND</sub> | ground current          |   |     | <b>−75</b> | -    | mA   |
| T <sub>stg</sub> | storage temperature     |   |     | -65        | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | $T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$          | [2] | -          | 250  | mW   |

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>[2]</sup> For both TSSOP5 and SC-74A packages: above 87.5  $^{\circ}$ C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 package: above 118  $^{\circ}$ C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter             | Conditions                                 | 74  | AHC1G | )4              | 74  | Unit |                 |      |
|------------------|-----------------------|--|-----|-------|-----------------|-----|------|-----------------|------|
|                  |                       |  | Min | Тур   | Max             | Min | Тур  | Max             |      |
| V <sub>CC</sub>  | supply voltage        |  | 2.0 | 5.0   | 5.5             | 4.5 | 5.0  | 5.5             | V    |
| VI               | input voltage         |  | 0   | -     | 5.5             | 0   | -    | 5.5             | V    |
| Vo               | output voltage        |  | 0   | -     | V <sub>CC</sub> | 0   | -    | V <sub>CC</sub> | V    |
| T <sub>amb</sub> | ambient temperature   |  | -40 | +25   | +125            | -40 | +25  | +125            | °C   |
| Δt/ΔV            | input transition rise | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | -   | -     | 100             | -   | -    | -               | ns/V |
|                  | and fall rate         | $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$ | -   | -     | 20              | -   | -    | 20              | ns/V |

## 10. Static characteristics

#### Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                                 | Conditions   |      | 25 °C |      | -40 °C | to +85 °C | -40 °C 1 | o +125 °C | Unit |
|-----------------|---|--|------|-------|------|--------|-----------|----------|-----------|------|
|                 |   |  | Min  | Тур   | Max  | Min    | Max       | Min      | Max       |      |
| 74AHC1          | G04                                       |  |      |       |      | 1      |           |          |           |      |
| $V_{IH}$        | HIGH-level                                | $V_{CC} = 2.0 \text{ V}$   | 1.5  | -     | -    | 1.5    | -         | 1.5      | -         | V    |
|                 | input voltage                             | V <sub>CC</sub> = 3.0 V  | 2.1  | -     | -    | 2.1    | -         | 2.1      | -         | V    |
|                 |   | V <sub>CC</sub> = 5.5 V  | 3.85 | -     | -    | 3.85   | -         | 3.85     | -         | V    |
| $V_{IL}$        | LOW-level                                 | V <sub>CC</sub> = 2.0 V  | -    | -     | 0.5  | -      | 0.5       | -        | 0.5       | V    |
|                 | input voltage                             | V <sub>CC</sub> = 3.0 V  | -    | -     | 0.9  | -      | 0.9       | -        | 0.9       | V    |
|                 |   | V <sub>CC</sub> = 5.5 V  | -    | -     | 1.65 | -      | 1.65      | -        | 1.65      | V    |
| $V_{OH}$        | HIGH-level                                | $V_I = V_{IH}$ or $V_{IL}$                                       |      |       |      |        |           |          |           |      |
|                 | output voltage                            | $I_O = -50 \mu A; V_{CC} = 2.0 V$                                | 1.9  | 2.0   | -    | 1.9    | -         | 1.9      | -         | V    |
|                 | $I_O = -50 \mu A; V_{CC} = 3.0 \text{ V}$ | 2.9  | 3.0  | -     | 2.9  | -      | 2.9       | -        | V         |      |
|                 |   | $I_O = -50 \mu A; V_{CC} = 4.5 V$                                | 4.4  | 4.5   | -    | 4.4    | -         | 4.4      | -         | V    |
|                 |   | $I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$                | 2.58 | -     | -    | 2.48   | -         | 2.40     | -         | V    |
|                 |   | $I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$                | 3.94 | -     | -    | 3.8    | -         | 3.70     | -         | V    |
| $V_{OL}$        | LOW-level                                 | $V_I = V_{IH}$ or $V_{IL}$                                       |      |       |      |        |           |          |           |      |
|                 | output voltage                            | $I_O = 50 \mu A; V_{CC} = 2.0 V$                                 | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                 |   | $I_O = 50 \mu A; V_{CC} = 3.0 V$                                 | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                 |   | $I_O = 50 \mu A; V_{CC} = 4.5 V$                                 | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                 |   | $I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$                   | -    | -     | 0.36 | -      | 0.44      | -        | 0.55      | V    |
|                 |   | $I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$                   | -    | -     | 0.36 | -      | 0.44      | -        | 0.55      | V    |
| l <sub>l</sub>  | input leakage<br>current                  | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V | -    | -     | 0.1  | -      | 1.0       | -        | 2.0       | μΑ   |
| I <sub>CC</sub> | supply current                            | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$     | -    | -     | 1.0  | -      | 10        | -        | 40        | μΑ   |
| Cı              | input<br>capacitance                      |  | -    | 1.5   | 10   | -      | 10        | -        | 10        | pF   |

**Table 7. Static characteristics** ...continued Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                 | Conditions   |      | 25 °C |      | -40 °C 1 | to +85 °C | –40 °C t | o +125 °C | Unit |
|------------------|---------------------------|--|------|-------|------|----------|-----------|----------|-----------|------|
|                  |                           |  | Min  | Тур   | Max  | Min      | Max       | Min      | Max       |      |
| 74AHCT           | 1G04                      |  |      |       |      |          |           |          | 1         |      |
| V <sub>IH</sub>  | HIGH-level input voltage  | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$   | 2.0  | -     | -    | 2.0      | -         | 2.0      | -         | V    |
| V <sub>IL</sub>  | LOW-level input voltage   | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$   | -    | -     | 0.8  | -        | 0.8       | -        | 0.8       | V    |
| V <sub>OH</sub>  | HIGH-level                | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$  |      |       |      |          |           |          |           |      |
| output voltage   | I <sub>O</sub> = -50 μA   | 4.4  | 4.5  | -     | 4.4  | -        | 4.4       | -        | V         |      |
|                  |                           | $I_{O} = -8.0 \text{ mA}$  | 3.94 | -     | -    | 3.8      | -         | 3.70     | -         | V    |
| $V_{OL}$         | LOW-level                 | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$  |      |       |      |          |           |          |           |      |
|                  | output voltage            | I <sub>O</sub> = 50 μA   | -    | 0     | 0.1  | -        | 0.1       | -        | 0.1       | V    |
|                  |                           | I <sub>O</sub> = 8.0 mA  | -    | -     | 0.36 | -        | 0.44      | -        | 0.55      | V    |
| l <sub>l</sub>   | input leakage<br>current  | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V   | -    | -     | 0.1  | -        | 1.0       | -        | 2.0       | μΑ   |
| I <sub>CC</sub>  | supply current            | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$  | -    | -     | 1.0  | -        | 10        | -        | 40        | μА   |
| Δl <sub>CC</sub> | additional supply current | per input pin; $V_I = 3.4 \text{ V}$ ;<br>other inputs at $V_{CC}$ or GND;<br>$I_O = 0 \text{ A}$ ; $V_{CC} = 5.5 \text{ V}$ | -    | -     | 1.35 | -        | 1.5       | -        | 1.5       | mA   |
| Cı               | input<br>capacitance      |  | -    | 1.5   | 10   | -        | 10        | -        | 10        | pF   |

## 11. Dynamic characteristics

### Table 8. Dynamic characteristics

GND = 0 V;  $t_r = t_f = \le 3.0$  ns. For test circuit see <u>Figure 7</u>.

| Symbol          | Parameter                           | Conditions  |            |   | 25 °C |      | -40 °C | to +85 °C | -40 °C t | o +125 °C | Unit |
|-----------------|-------------------------------------|---|------------|---|-------|------|--------|-----------|----------|-----------|------|
|                 |                                     |   |            |   | Тур   | Max  | Min    | Max       | Min      | Max       |      |
| 74AHC1          | G04                                 | '   |            |   |       |      |        | 1         |          |           |      |
| t <sub>pd</sub> | propagation                         | A to Y; see Figure 6  | [1]        |   |       |      |        |           |          |           |      |
|                 | delay                               | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$  | [2]        |   |       |      |        |           |          |           |      |
|                 |                                     | C <sub>L</sub> = 15 pF  |            | - | 4.3   | 7.1  | 1.0    | 8.5       | 1.0      | 11.0      | ns   |
|                 |                                     | C <sub>L</sub> = 50 pF  |            | - | 6.1   | 10.6 | 1.0    | 12        | 1.0      | 14.5      | ns   |
|                 |                                     | V <sub>CC</sub> = 4.5 V to 5.5 V  | [3]        |   |       |      |        |           |          |           |      |
|                 |                                     | C <sub>L</sub> = 15 pF  |            | - | 3.1   | 5.5  | 1.0    | 6.5       | 1.0      | 7.0       | ns   |
|                 |                                     | C <sub>L</sub> = 50 pF  |            | - | 4.5   | 7.5  | 1.0    | 8.5       | 1.0      | 9.5       | ns   |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | per buffer; [4] $C_L = 50 \text{ pF; } f = 1 \text{ MHz;}$ $V_I = \text{GND to } V_{CC}$      |            | - | 15    | -    | -      | -         | -        | -         | pF   |
| 74AHCT          | 1G04                                |   |            |   |       | 1    | -      | 1         | -        | -         | -    |
| t <sub>pd</sub> | propagation                         | A to Y; see Figure 6  | <u>[1]</u> |   |       |      |        |           |          |           |      |
|                 | delay                               | V <sub>CC</sub> = 4.5 V to 5.5 V  | [3]        |   |       |      |        |           |          |           |      |
|                 |                                     | C <sub>L</sub> = 15 pF  |            | - | 3.4   | 6.7  | 1.0    | 7.5       | 1.0      | 8.5       | ns   |
|                 |                                     | C <sub>L</sub> = 50 pF  |            | - | 4.9   | 7.7  | 1.0    | 8.5       | 1.0      | 10.0      | ns   |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | per buffer;<br>$C_L = 50 \text{ pF}$ ; $f = 1 \text{ MHz}$ ;<br>$V_I = \text{GND to } V_{CC}$ | <u>[4]</u> | - | 16    | -    | -      | -         | -        | -         | pF   |

- [1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [2] Typical values are measured at  $V_{CC}$  = 3.3 V.
- [3] Typical values are measured at  $V_{CC} = 5.0 \text{ V}$ .
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i$  +  $\sum$  (C\_L  $\times$  V\_{CC}{}^2 \times f\_o) where:

 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts;

N = total load switching outputs;

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$  = sum of outputs.

### 12. Waveforms

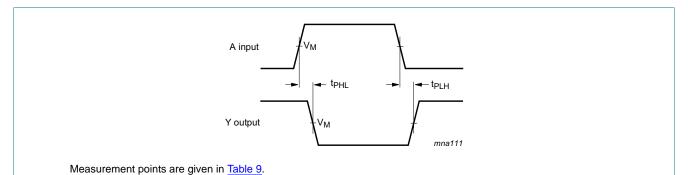
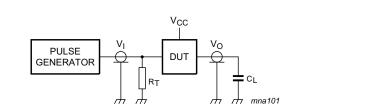


Fig 6. Input (A) to output (Y) propagation delays

#### Table 9. Measurement point

| Туре       | Input                  | Input               | Output              |
|------------|------------------------|---------------------|---------------------|
|            | V <sub>I</sub>         | V <sub>M</sub>      | V <sub>M</sub>      |
| 74AHC1G04  | GND to V <sub>CC</sub> | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |
| 74AHCT1G04 | GND to 3.0 V           | 1.5 V               | $0.5 \times V_{CC}$ |



Test data is given in  $\underline{\text{Table 8}}$ . Definitions for test circuit:

 $C_L$  = Load capacitance including jig and probe capacitance.

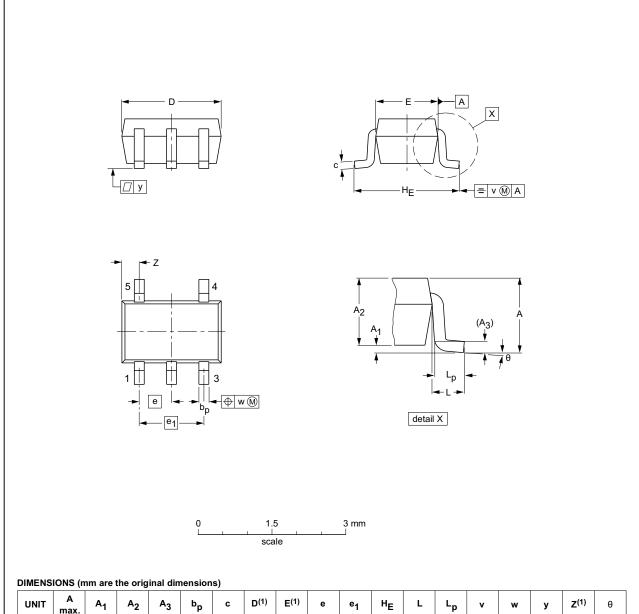
 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

Fig 7. Test circuit for measuring switching times

## 13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



| UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | b <sub>p</sub> | С            | D <sup>(1)</sup> | E(1)         | е    | e <sub>1</sub> | HE          | L     | Lp           | v   | w   | у   | Z <sup>(1)</sup> | θ        |
|------|-----------|----------------|----------------|----------------|----------------|--------------|------------------|--------------|------|----------------|-------------|-------|--------------|-----|-----|-----|------------------|----------|
| mm   | 1.1       | 0.1<br>0       | 1.0<br>0.8     | 0.15           | 0.30<br>0.15   | 0.25<br>0.08 | 2.25<br>1.85     | 1.35<br>1.15 | 0.65 | 1.3            | 2.25<br>2.0 | 0.425 | 0.46<br>0.21 | 0.3 | 0.1 | 0.1 | 0.60<br>0.15     | 7°<br>0° |

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE  |     | REFER  | RENCES | EUROPEAN   | ISSUE DATE                      |  |
|----------|-----|--------|--------|------------|---------------------------------|--|
| VERSION  | IEC | JEDEC  | JEITA  | PROJECTION | ISSUE DATE                      |  |
| SOT353-1 |     | MO-203 | SC-88A |            | <del>00-09-01</del><br>03-02-19 |  |

Fig 8. Package outline SOT353-1 (TSSOP5)

74AHC\_AHCT1G04

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### Plastic surface-mounted package; 5 leads

### **SOT753**

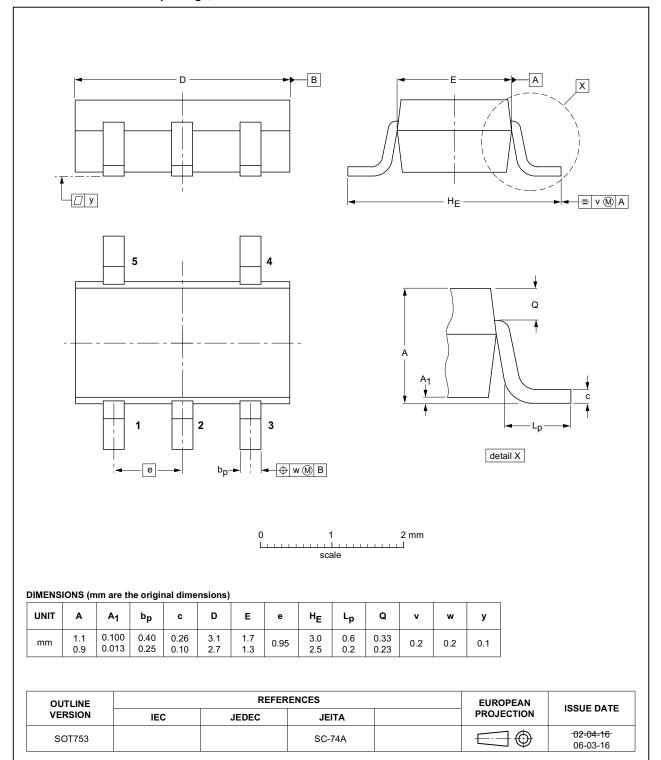


Fig 9. Package outline SOT753 (SC-74A)

74AHC\_AHCT1G04

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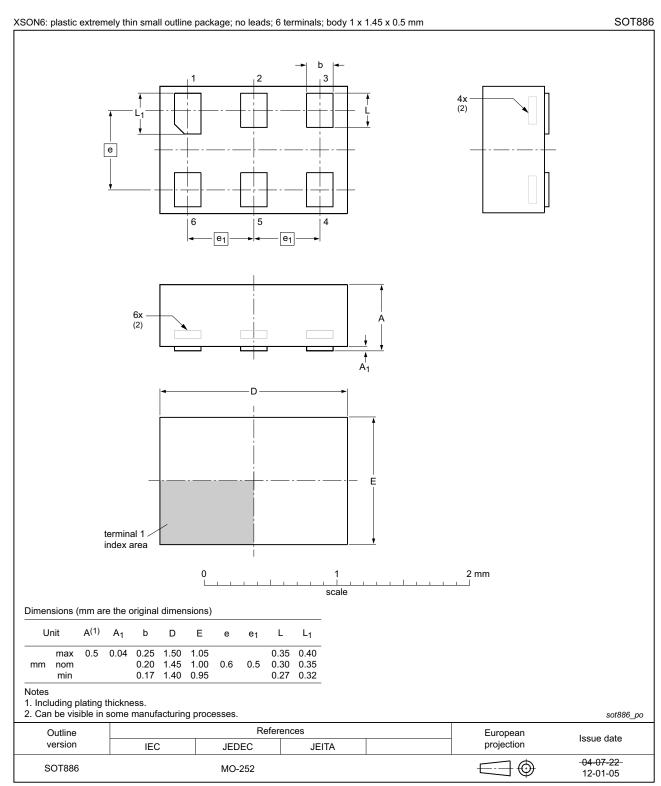


Fig 10. Package outline SOT886 (XSON6)

74AHC\_AHCT1G04

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## 14. Abbreviations

#### Table 10. Abbreviations

| Acronym | Description                 |
|---------|-----------------------------|
| CDM     | Charged Device Model        |
| DUT     | Device Under Test           |
| ESD     | ElectroStatic Discharge     |
| НВМ     | Human Body Model            |
| MM      | Machine Model               |
| TTL     | Transistor-Transistor Logic |

## 15. Revision history

### Table 11. Revision history

| Document ID          | Release date                                     | Data sheet status  | Change notice       | Supersedes           |  |  |
|----------------------|--|--|---------------------|----------------------|--|--|
| 74AHC_AHCT1G04 v.9   | 20150310   | Product data sheet   | -                   | 74AHC_AHCT1G04 v.8   |  |  |
| Modifications:       | Added type numbers 74AHC1G04GM and 74AHCT1G04GM. |  |                     |                      |  |  |
| 74AHC_AHCT1G04 v.8   | 20141106   | Product data sheet   | -                   | 74AHC_AHCT1G04 v.7   |  |  |
| Modifications:       | • Section 4:                                     | • Section 4: table note added.                             |                     |                      |  |  |
| 74AHC_AHCT1G04 v.7   | 20070531   | Product data sheet   | -                   | 74AHC_AHCT1G04 v.6   |  |  |
| Modifications:       | guidelines                                       | t of this data sheet has been re<br>of NXP Semiconductors. |                     | ·                    |  |  |
|                      | _  | s have been adapted to the new                             | · •                 |                      |  |  |
|                      | <ul> <li>Package S</li> </ul>                    | OT353 changed to SOT353-1                                  | in Section 3 and Se | ection 13.           |  |  |
|                      | <ul> <li>Quick refe</li> </ul>                   | rence data and Soldering secti                             | ions removed.       |                      |  |  |
| 74AHC_AHCT1G04 v.6   | 20030904   | Product specification                                      | -                   | 74AHC_AHCT1G04 v.5   |  |  |
| 74AHC_AHCT1G04 v.5   | 20020527   | Product specification                                      | -                   | 74AHC_AHCT1G04 v.4   |  |  |
| 74AHC_AHCT1G04 v.4   | 20020215   | Product specification                                      | -                   | 74AHC_AHCT1G04 v.3   |  |  |
| 74AHC_AHCT1G04 v.3   | 20010131   | Product specification                                      | -                   | 74AHC_AHCT1G04 v.2   |  |  |
| 74AHC_AHCT1G04 v.2   | 19990127   | Product specification                                      | -                   | 74AHC_AHCT1G04_N v.1 |  |  |
| 74AHC_AHCT1G04_N v.1 | 19981125   | Preliminary specification                                  | -                   | -                    |  |  |

## 16. Legal information

#### 16.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
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- [1] Please consult the most recently issued document before initiating or completing a design.
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